



Cite this: *Chem. Commun.*, 2015, 51, 8640

Received 8th March 2015,  
Accepted 14th April 2015

DOI: 10.1039/c5cc01966d

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**Sb<sub>2</sub>S<sub>3</sub>** sensitized solar cells are a promising alternative to devices employing organic dyes. The manufacture of Sb<sub>2</sub>S<sub>3</sub> absorber layers is however slow and cumbersome. Here, we report the modified aqueous chemical bath synthesis of Sb<sub>2</sub>S<sub>3</sub> absorber layers for sensitized solar cells. Our method is based on the hydrolysis of SbCl<sub>3</sub> to complex antimony ions decelerating the reaction at ambient conditions, in contrast to the usual low temperature deposition protocol. This simplified deposition route allows the manufacture of sensitized mesoporous-TiO<sub>2</sub> solar cells with power conversion efficiencies up to  $\eta = 5.1\%$ . Photothermal deflection spectroscopy shows that the sub-bandgap trap-state density is lower in Sb<sub>2</sub>S<sub>3</sub> films deposited with this method, compared to standard deposition protocols.

Antimony sulfide (Sb<sub>2</sub>S<sub>3</sub>) is a promising material for several optoelectronic applications. Due to its high absorption coefficient ( $\alpha \approx 1.8 \times 10^5 \text{ cm}^{-1}$  at  $\lambda = 450 \text{ nm}$ ) and a suitable direct bandgap of  $E_g \approx 1.7 \text{ eV}$ , crystalline Sb<sub>2</sub>S<sub>3</sub> (stibnite) is interesting as light absorber for solid-state sensitized solar cells (Fig. 1).<sup>1,2</sup> In particular, Sb<sub>2</sub>S<sub>3</sub>-based solar cells excel in their stability of operation when compared to other organic-inorganic hybrid devices. Recently, power-conversion efficiencies of  $\eta = 6.2\%$  (ref. 3) and  $\eta = 7.5\%$  (ref. 4) were achieved using Sb<sub>2</sub>S<sub>3</sub> as the absorber material obtained from chemical bath deposition. Further, the material has been used to improve the stability of methyl-ammonium lead iodide perovskite solar cells.<sup>5</sup>

Antimony sulfide synthesis typically involves deposition in aqueous and non-aqueous chemical baths at low temperatures

## Efficient room temperature aqueous Sb<sub>2</sub>S<sub>3</sub> synthesis for inorganic–organic sensitized solar cells with 5.1% efficiencies†

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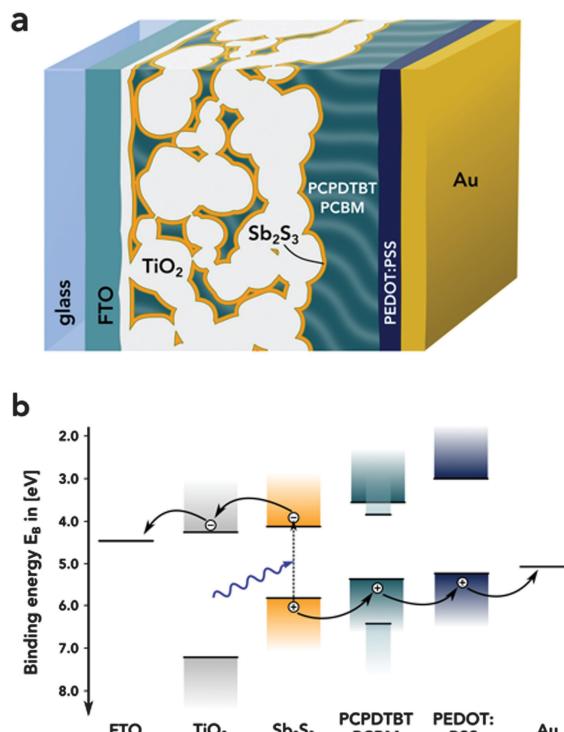


Fig. 1 (a) Schematic of the solar cell cross section. (b) Simplified band-diagram of the Sb<sub>2</sub>S<sub>3</sub> sensitised photovoltaic cells. The band edge values were taken from ref. 10.

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† Electronic supplementary information (ESI) available. See DOI: 10.1039/c5cc01966d

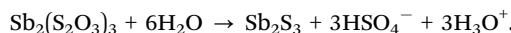
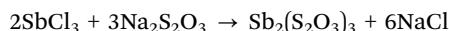
(low-T deposition).<sup>6–9</sup> The standard method is the aqueous chemical bath deposition (CBD) using antimony chloride and sodium thiosulfate. This technique is however problematic since it requires a precise temperature control of the solution when cooling below 10 °C and maintaining the sample at low temperatures. For large-scale applications such a cooling protocol is cumbersome, costly and energy-intensive.

Here, we present an aqueous room temperature (RT) deposition route of Sb<sub>2</sub>S<sub>3</sub> using the same precursor materials as the standard CBD method. We have fabricated Sb<sub>2</sub>S<sub>3</sub>-sensitized



solar cells using this RT deposition method and demonstrate excellent device performance with efficiencies of up to  $\eta = 5.1\%$ .

The low-temperature synthesis of  $\text{Sb}_2\text{S}_3$  for photovoltaic applications involves the chemical reaction equations<sup>7</sup>



These reactions have to be slowed down by cooling below 10 °C to avoid immediate precipitation<sup>7</sup> and to enable strong adhesion of  $\text{Sb}_2\text{S}_3$  to the substrate. Thus, the standard CBD method, termed low-T deposition, requires cooling of the reaction solution, whereas our modified method, RT deposition, can be performed at room temperature. By changing the order of reactant addition at RT,  $\text{Sb}_2\text{S}_3$  formation is slowed down and well-adhering films are obtained.

For the RT deposition, a 1.4 M  $\text{SbCl}_3$  solution in acetone was prepared. Note that the optimal concentration of  $\text{SbCl}_3$  for the RT method is slightly higher compared to low-T deposition (Fig. S7, ESI†).  $\text{SbCl}_3$  can be used without dissolution in acetone, changing the reaction behaviour very little (Fig. S8, ESI†). The addition of acetone facilitates however the handling of the highly hygroscopic  $\text{SbCl}_3$ . Deionised water is added under vigorous stirring to reduce the total concentration of  $\text{SbCl}_3$  to 46 mM. The addition of water hydrolyses  $\text{SbCl}_3$ , which leads to a solid white precipitate. The product of the hydrolysis reaction of  $\text{SbCl}_3$  is not very well defined. It depends on many parameters such as the dilution of the reaction medium, the pH value of the solution and solvent composition.<sup>11,12</sup> The aqueous solution containing the hydrolysed  $\text{SbCl}_3$  has a pH of 1.4.

The precipitate was filtered and dried and X-ray diffraction (XRD), Fourier transform infrared spectroscopy (FTIR) and energy-dispersive X-ray (EDX) spectroscopy were performed on the white powder (Fig. S10–S12, ESI†). The XRD pattern shows crystalline phases of  $\text{Sb}_4\text{O}_5\text{Cl}_2$ ,  $\text{Sb}_8(\text{OH})_6\text{O}_8\text{Cl}_2(\text{H}_2\text{O})$ ,  $\text{Sb}_8\text{O}_{11}\text{Cl}_2(\text{H}_2\text{O})_6$  and  $\text{Sb}_3\text{O}_6(\text{OH})$ . This is in contrast to the reports by Li *et al.* and Yu *et al.* describing similar reactions.<sup>13,14</sup> They also reporting the formation of a white precipitate, which they identify as antimony oxychloride  $\text{SbOCl}$ . The XRD pattern of Fig. S10 (ESI†) however shows no evidence of crystalline  $\text{SbOCl}$  formation. According to Chen *et al.* hydrolysis at pH 1–2 leads to the formation of  $\text{Sb}_4\text{O}_5\text{Cl}_2$  for mixed solvents such as water and ethanol or water and ethylene glycol.<sup>12</sup> We also do not observe an immediate colour change of the precipitate to orange upon the addition of the sulphur source, as reported by Li *et al.*<sup>13</sup> and Yu *et al.*<sup>14</sup>

Subsequently, a 1 M aqueous  $\text{Na}_2\text{S}_2\text{O}_3$  solution was added at a final concentration of 0.25 M in the chemical bath. This causes the solution to turn clear as most of the precipitate dissolves, suggesting the formation of a water-soluble complex. After 5–10 min at 20 °C, the solution starts to turn orange, indicating the formation of amorphous  $\text{Sb}_2\text{S}_3$ . This is accompanied by a pH change of the solution from pH = 3.3 upon sodium thiosulfate (pH = 7.3) addition to pH = 4.3 when antimony sulfide deposition is complete after two hours.

Fig. S2 (ESI†) shows the UV-vis spectra of RT-deposited  $\text{Sb}_2\text{S}_3$  films on mesoporous-TiO<sub>2</sub>, annealed at 300 °C for 5 min.

The annealed antimony sulfide was characterised by powder X-ray diffraction (XRD). Fig. 3a compares the XRD pattern of the low-T and RT deposition methods. Both pattern are very similar and match the stibnite reference pattern.<sup>15</sup>  $\text{Sb}_2\text{S}_3$  films deposited by the RT method onto mesoporous TiO<sub>2</sub> substrates also show the characteristic XRD peaks of crystalline  $\text{Sb}_2\text{S}_3$  (Fig. S3, ESI†). A Rietveld analysis of the two patterns using the powder diffraction software ReX<sup>16</sup> yields an average  $\text{Sb}_2\text{S}_3$  crystallite size of 40 nm and 35 nm for RT and low-T deposition, respectively. The structure of the solar cell studied in this work and a schematic band diagram are shown in Fig. 1.

Fig. 2 shows (a) the current–voltage characteristic and (b) the external quantum efficiency EQE of the best performing solar cell employing RT deposited  $\text{Sb}_2\text{S}_3$ . Its photovoltaic parameters are summarised in Fig. 2. The shunt and series resistances were obtained by a least square fit of the diode function. The RT method enables the fabrication of solar cells with high reproducibility. The deviations from batch to batch and from device to device were small (Fig. S13, ESI†). The hole transport layer consists of a PCPDTBT–PCBM blend. Charge carriers which are generated by photon absorption in the hole transport

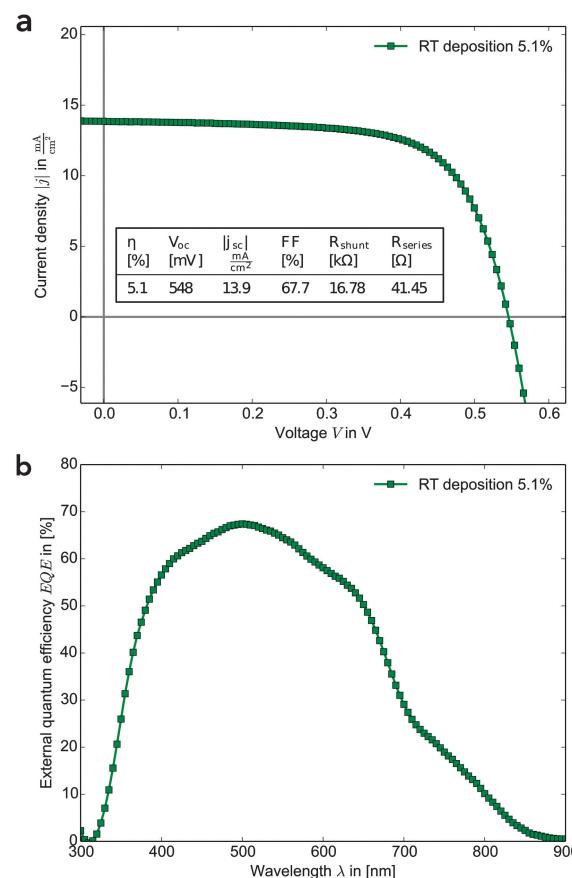


Fig. 2 (a) Current–voltage curve of the best performing solar cell device employing  $\text{Sb}_2\text{S}_3$  synthesised using the RT method. The inset table shows the photovoltaic parameters of the device. (b) External quantum efficiency of the device.



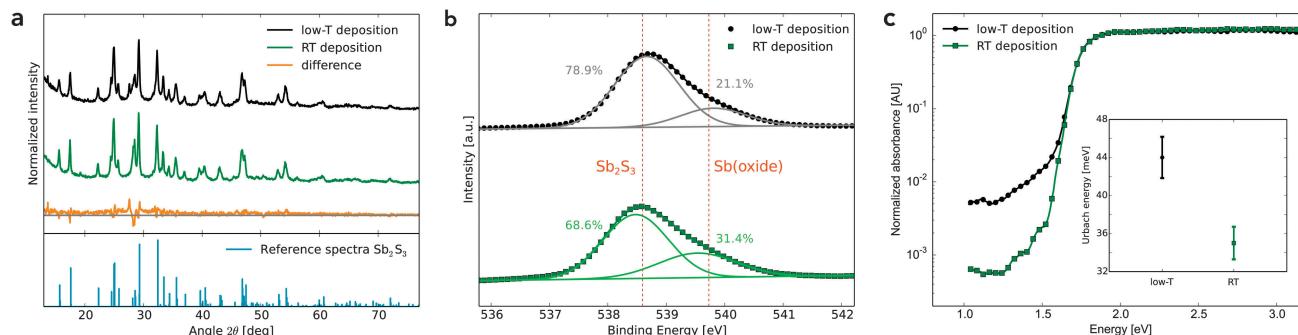


Fig. 3 (a) XRD pattern of crystalline  $\text{Sb}_2\text{S}_3$ , synthesised via the low temperature deposition method (upper trace) and the RT technique (center trace). The lower trace shows the difference of the two patterns. The stibnite reference pattern was taken from ref. 15. (b) XPS  $\text{Sb}3\text{d}_{3/2}$  peak of films from both deposition methods. (c) PDS measurements showing the sub band-gap energy levels for both deposition methods. The inset shows the corresponding Urbach energies.

layer can also be harvested due to the formation of PCBM electron conducting channels. The PCBM-PCPDTBT blend thus contributes to the current and causes the near-infrared shoulder in the EQE spectrum.<sup>17</sup> Earlier cells using P3HT as hole conductor showed lower efficiencies compared to the PCPDTBT:PCBM blend. We therefore concentrated on the donor-acceptor PCPDTBT-PCBM blend. A comparison of a RT solar cell and a solar cell with the same device architecture using the low-temperature deposition method is shown in the ESI† (Fig. S4). The reference cells were prepared in the same laboratory using the identical procedures as the better performing earlier published devices.<sup>4</sup> The lower performance may reflect the variation in this system that possibly arises from minor variations in device fabrication. It is however important to point out that the reference devices and devices made with our new methodology were created in parallel and therefore are much less likely to be subject to this type of variation.

X-ray photoelectron spectroscopy (XPS) measurements were carried out on  $\text{Sb}_2\text{S}_3$  films formed by both deposition techniques, shown in Fig. 3b.

To compare the oxide content of the samples, the antimony  $\text{Sb}3\text{d}_{3/2}$  peak was examined, because the oxygen O1s peak directly overlaps with the antimony  $\text{Sb}3\text{d}_{3/2}$  peak. The  $\text{Sb}3\text{d}_{3/2}$  peak can be modelled using a superposition of two Gaussians, one at  $\approx 538.5$  eV representing  $\text{Sb}_2\text{S}_3$  and one at  $\approx 539.5$  eV for  $\text{SbO}_x$ , most likely  $\text{Sb}_2\text{O}_3$ .<sup>18</sup> The RT sample has a marginally higher oxide content compared to the low-T material. This probably causes the lower conductivity seen in these films (Fig. S6, ESI†).

One of the biggest challenges of using antimony sulfide as absorber in sensitized solar cells is the high density of electronic traps in this material, *i.e.* the number of energy states which lie in the band-gap of  $\text{Sb}_2\text{S}_3$ .<sup>4,19</sup> These trap-states lead to a significant loss in potential and to charge carrier recombination in the solar cell. To explore this, we employed photo-thermal deflection spectroscopy (PDS) to determine the trap-state density and the energetic disorder of  $\text{Sb}_2\text{S}_3$ . PDS is a highly sensitive absorption measurement technique, which can detect absorbance values down to  $10^{-5}$  AU. Thus, PDS is able to accurately measure weak absorption in the bandgap. Fig. 3c shows the PDS spectra of  $\text{Sb}_2\text{S}_3$  samples on mesoporous  $\text{TiO}_2$  for both deposition methods. The corresponding Urbach energies are given in the inset.

The absorption in the RT-deposited sample was significantly lower at energies below the band-gap of  $\text{Sb}_2\text{S}_3$  compared to the low-T sample, by nearly one order of magnitude at energies below 1.5 eV. This indicates a clear reduction in the density of deep-trap states for the RT deposited  $\text{Sb}_2\text{S}_3$ . The difference in the open-circuit voltage for low-T and RT deposited  $\text{Sb}_2\text{S}_3$  in optimized solar cells are however similar (Fig. S4, ESI†). As the band-gap of antimony oxide is higher than that of  $\text{Sb}_2\text{S}_3$ ,<sup>20</sup> the PDS spectrum cannot show a potential increase of deep traps caused by the higher content of antimony oxide in the RT-deposited sample.

We have demonstrated an aqueous deposition technique of antimony sulfide for sensitized solar cells, which can be carried out at room temperature. The chemical bath deposition method is based on the same precursor materials but uses the hydrolysis of  $\text{SbCl}_3$  to complex antimony ions. The resulting  $\text{Sb}_2\text{S}_3$  films were investigated using UV-vis spectroscopy, XRD, PDS and XPS. PDS shows a reduction in sub-band gap trap states in RT-deposited  $\text{Sb}_2\text{S}_3$ . Manufactured devices achieved a maximum power conversion efficiency  $\eta = 5.1\%$  for  $\text{Sb}_2\text{S}_3$  sensitized solar cells using the RT deposition method. A more detailed optimization of the deposition step, interfacial surface treatments<sup>21,22</sup> or doping of the  $\text{Sb}_2\text{S}_3$ <sup>23</sup> could lead to a further improvement in solar cell performance. This work is therefore an important step in the development of low-cost, stable and highly efficient solar cells.

We acknowledge Adam Brown's help with the XPS measurements. K.C.G. would like to thank the Cambridge Trust, the Mott Fund for Physics of the Environment and Corpus Christi College Cambridge for funding. A.S. acknowledges funding from the Engineering and Physical Sciences Research Council (EPSRC).

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